

IFN860 Dual Matched N-Channel JFET

Features

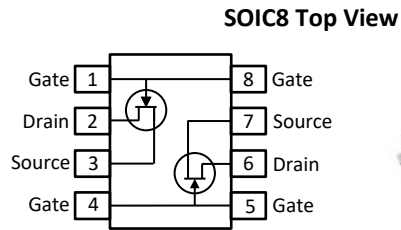
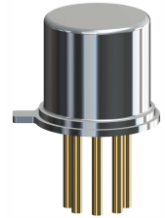
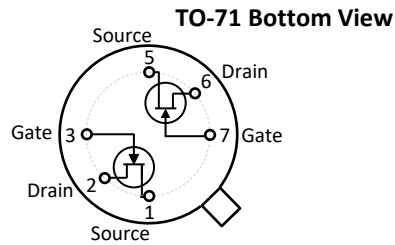
- InterFET [N0450L Geometry](#)
- Low Noise: 0.9 nV/√Hz Typical
- High Gain: 40mS Typical
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

Applications

- Low-Noise Audio Amplifier
- Similar to Crystalonics CD860

Description

The -20V InterFET IFN860 JFET is targeted for low noise high gain amplifier stages for mid-frequencies designs. The TO-71 package is hermetically sealed and suitable for military applications. Custom specifications, matching, and packaging options are available.



Product Summary

Parameters		IFN860 Min	Unit
BV_{GS}	Gate to Source Breakdown Voltage	-20	V
I_{DSS}	Drain to Source Saturation Current	10	mA
$V_{GS(off)}$	Gate to Source Cutoff Voltage	-0.3	V
G_{FS}	Forward Transconductance	25	mS

Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
IFN860	Through-Hole	TO-71	Bulk
SMP860	Surface Mount	SOIC8	Bulk
SMP860TR	7" Tape and Reel: Max 3,000 Pieces 13" Tape and Reel: Max 9,000 Pieces	SOIC8	Minimum 1,000 Pieces Tape and Reel
IFN860COT *	Chip Orientated Tray (COT Waffle Pack)	COT	70/Waffle Pack
IFN860CFT *	Chip Face-up Tray (CFT Waffle Pack)	CFT	70/Waffle Pack

* Bare die packaged options are designed for matched specifications but not 100% tested



Disclaimer: It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.

Electrical Characteristics

Maximum Ratings (@ $T_A = 25^\circ\text{C}$, Unless otherwise specified)

Parameters	Value	Unit
V_{RGS} Reverse Gate Source and Gate Drain Voltage	-20	V
I_{FG} Continuous Forward Gate Current	50	mA
P_D Continuous Device Power Dissipation	400	mW
P Power Derating	2.3	mW/ $^\circ\text{C}$
T_J Operating Junction Temperature	-55 to 125	$^\circ\text{C}$
T_{STG} Storage Temperature	-65 to 200	$^\circ\text{C}$

Static Characteristics (@ $T_A = 25^\circ\text{C}$, Unless otherwise specified)

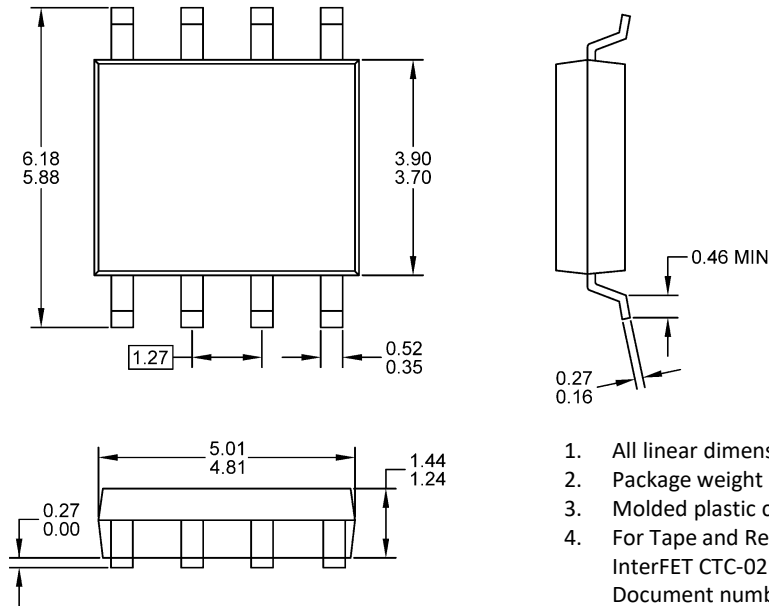
Parameters	Conditions	IFN860		Unit
		Min	Max	
$V_{(BR)GSS}$ Gate to Source Breakdown Voltage	$V_{DS} = 0\text{V}, I_G = -1\mu\text{A}$	-20		V
I_{GSS} Gate to Source Reverse Current	$V_{GS} = -10\text{V}, V_{DS} = 0\text{V}$		3	nA
$V_{GS(OFF)}$ Gate to Source Cutoff Voltage	$V_{DS} = 10\text{V}, I_D = 100\mu\text{A}$	-0.3	-3	V
I_{DSS} Drain to Source Saturation Current	$V_{GS} = 0\text{V}, V_{DS} = 10\text{V}$ (Pulsed)	10		mA
$ V_{GS1} - V_{GS2} $ Differential Gate Source Voltage	$V_{DS} = 10\text{V}, I_D = 100\mu\text{A}$		25	mV

Dynamic Characteristics (@ $T_A = 25^\circ\text{C}$, Unless otherwise specified)

Parameters	Conditions	IFN860			Unit
		Min	Typ	Max	
G_{FS} Forward Transconductance	$V_{DS} = 10\text{V}, I_D = -10\text{mA}, f = 1\text{kHz}$	25	40		mS
C_{iss} Input Capacitance	$V_{DS} = 10\text{V}, I_D = -10\text{mA}, f = 1\text{MHz}$		30	35	pF
C_{rss} Reverse Transfer Capacitance	$V_{DS} = 10\text{V}, I_D = -10\text{mA}, f = 1\text{MHz}$		17	20	pF
e_n Equivalent Circuit Input Noise Voltage	$V_{DG} = 3\text{V}, I_D = 10\text{mA}, f = 1\text{kHz}$			2	nV/ $\sqrt{\text{Hz}}$

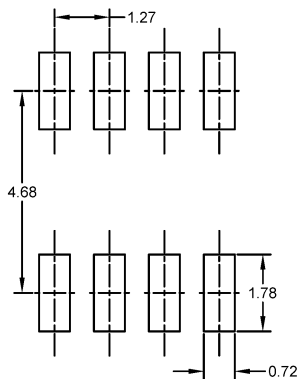
SOIC8 Mechanical and Layout Data

Package Outline Data



1. All linear dimensions are in millimeters.
2. Package weight approximately 0.21 grams
3. Molded plastic case UL 94V-0 rated
4. For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
5. Bulk product is shipped in standard ESD shipping material
6. Refer to JEDEC standards for additional information.

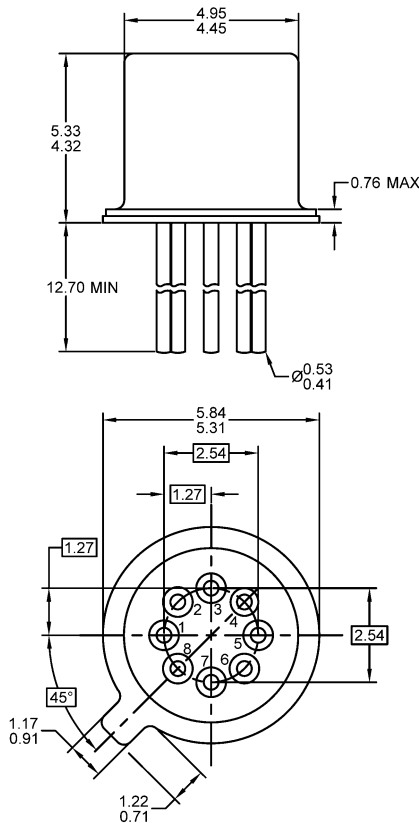
Suggested Pad Layout



1. All linear dimensions are in millimeters.
2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.

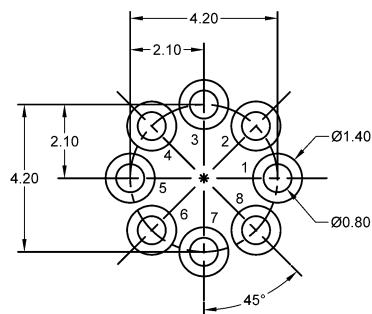
TO-71 Mechanical and Layout Data

Package Outline Data



1. All linear dimensions are in millimeters.
2. Eight leaded device. Not all leads are shown in drawing views.
3. Some package configurations will not populate pin 8 and/or pin 4.
4. Package weight approximately 0.35 grams
5. Bulk product is shipped in standard ESD shipping material
6. Refer to JEDEC standards for additional information.

Suggested Bent Lead Through-Hole Layout



1. All linear dimensions are in millimeters.
2. Pads 8 and/or pad 4 can be eliminated for devices with less pins.
3. The suggested land pattern dimensions have been provided as an eight pin bent lead reference only. A more robust pattern may be desired for wave soldering or reduced pin count.

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